

TECHNICAL DATA
DATA SHEET 255, REV. D
Formerly SHD1154/B

HERMETIC POWER SCHOTTKY RECTIFIER
200°C Maximum Operation Temperature

MAXIMUM RATINGS

ALL RATINGS ARE @ $T_c = 25^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED.

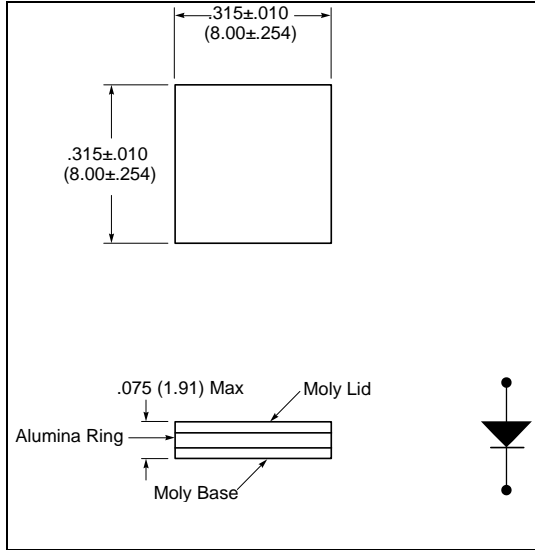
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	100	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_c=100^\circ\text{C}$)	I_o	60	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT ($t=10\text{ms}$, Sine)	I_{FSM}	700	Amps
MAXIMUM JUNCTION CAPACITANCE ($V_r=5\text{V}$)	C_T	1500	pF
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R\theta_{JC}$	0.70	$^\circ\text{C/W}$
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to +200	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS

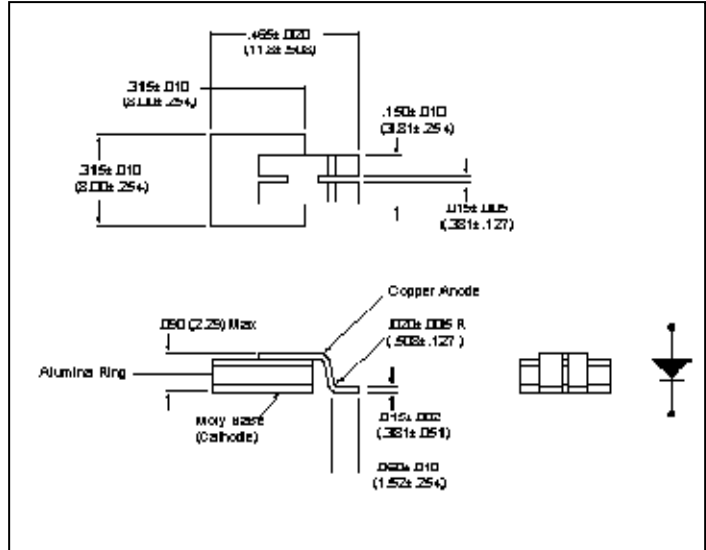
CHARACTERISTIC			
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (per leg, $I_f = 60$ Amps) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	V_f	0.87 0.72	Volts
MAXIMUM REVERSE CURRENT (per leg, I_r @ 100 V PIV) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	I_r	1.0 24.0	mA

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MECHANICAL DIMENSIONS: In Inches / mm



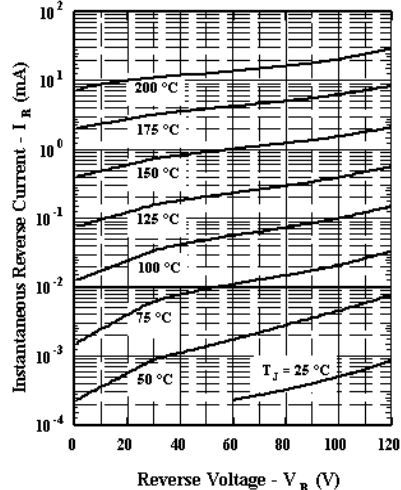
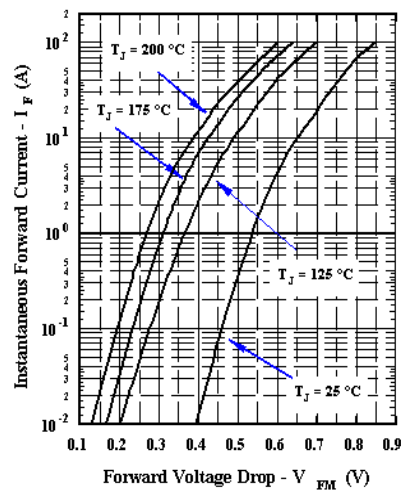
SHD-2



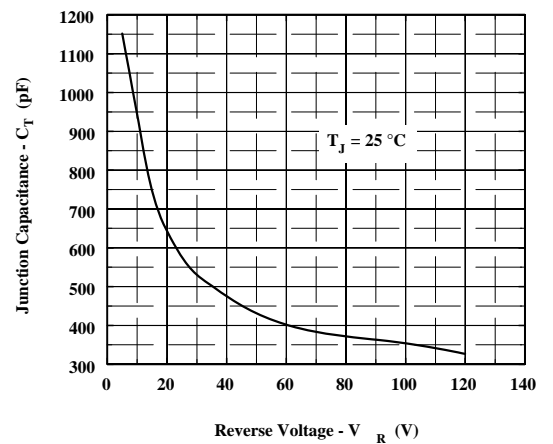
SHD-2B

Typical Forward Characteristics

Typical Reverse Characteristics



Typical Junction Capacitance



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